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May 2001

# FDS9953A

# Dual 30V P-Channel PowerTrench<sup>®</sup> MOSFET

## **General Description**

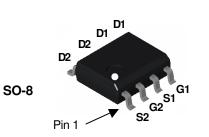
This P.Channel MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications requiring a wide range of gave drive voltage ratings (4.5V - 25V).

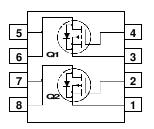
# Applications

- Power management
- Load switch
- Battery protection

# Features

- -2.9 A, -30 V  $R_{DS(ON)} = 130 \text{ m}\Omega @ V_{GS} = -10 \text{ V}$  $R_{DS(ON)} = 200 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}$
- Low gate charge (2.5nC typical)
- Fast switching speed
- High performance trench technology for extremely low  $R_{\text{DS}(\text{ON})}$
- High power and current handling capability





# Absolute Maximum Ratings T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter			Ratings	Units
V <sub>DSS</sub>	Drain-Source Voltage			-30	V
V <sub>GSS</sub>	Gate-Source Voltage			±25	
D	Drain Currer	nt – Continuous	(Note 1a)	±2.9	A
		– Pulsed		±10	
PD	Power Dissipation for Dual Operation			2	W
	Power Dissipation for Single Operation		n (Note 1a)	1.6	
			(Note 1b)	1	
			(Note 1c)	0.9	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		erature Range	-55 to +150	
Therma	l Charact	eristics	·		
R <sub>0JA</sub>	Thermal Res	Thermal Resistance, Junction-to-Ambient		78	°C/W
R <sub>0JC</sub>	Thermal Resistance, Junction-to-Case (Note 1)		e (Note 1)	40	°C/W
Packag	e Marking	and Ordering Ir	nformation		
Device Marking		Device	Reel Size	Tape width	Quantity
FDS9953A		FDS9953A	13"	12mm	2500 units

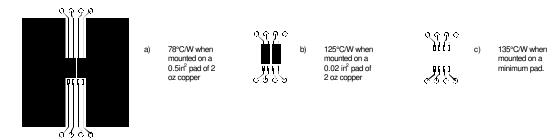
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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV <sub>DSS</sub>	Drain–Source Breakdown	$V_{GS} = 0 V, I_D = -250 \mu A$	-30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Voltage Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu A$ , Referenced to 25°C		-23		mV/°C
bss	Zero Gate Voltage Drain Current	$V_{DS} = -24 \text{ V}, \qquad V_{GS} = 0 \text{ V}$			-2	μA
GSSF	Gate-Body Leakage, Forward	$V_{GS} = -25 \text{ V}, \qquad V_{DS} = 0 \text{ V}$			-100	nA
GSSR	Gate–Body Leakage, Reverse	$V_{GS}=25~V, \qquad V_{DS}=0~V$			100	nA
On Chara	acteristics (Note 2)					1
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-1	-1.8	-3.0	V
$\Delta V_{GS(th)} \Delta T_J$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$ , Referenced to 25°C		4		mV/°C
R <sub>DS(on)</sub>	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = -10 \ V, \ b = -1 \ A \\ V_{GS} = -10 \ V, \ b = -1 \ A, \ T_J = 125^\circ C \\ V_{GS} = -4.5 \ V, \ b = -0.5 \ A \\ V_{GS} = -4.5 \ V, \ b = -0.5 \ A, \ T_J = 125^\circ C \\ V_{GS} = -10 \ V, \ V_{DS} = -5 \ V \\ \end{array} $		95 137 142 202	130 200 200 310	mΩ
I <sub>D(on)</sub>	On-State Drain Current	$V_{GS} = -10 V$ , $V_{DS} = -5 V$ $V_{GS} = -4.5 V$ , $V_{DS} = -5 V$	-5 -1.5			A
<b>g</b> <sub>FS</sub>	Forward Transconductance	$V_{DS} = -15 V$ , $I_D = -1 A$		4		S
-	Characteristics					
C <sub>iss</sub>	Input Capacitance			185		pF
Coss	Output Capacitance	$V_{DS} = -15 V$ , $V_{GS} = 0 V$ ,		56		pF
Crss	Reverse Transfer Capacitance	f = 1.0 MHz		26		pF
Switchin	g Characteristics (Note 2)		1		l	
t <sub>d(on)</sub>	Turn-On Delay Time	$V_{DD} = -15 V$ , $I_D = -1 A$ ,		4.5	9	ns
t <sub>r</sub>	Turn–On Rise Time	$V_{GS} = -10 \text{ V}, \qquad R_{GEN} = 6 \ \Omega$		13	23	ns
t <sub>d(off)</sub>	Turn–Off Delay Time			11	20	ns
tf	Turn–Off Fall Time			2	4	ns
Qq	Total Gate Charge	$V_{DS} = -5 V$ , $I_D = -1 A$ ,		2.5	3.5	nC
Q <sub>gs</sub>	Gate–Source Charge	$V_{GS} = -10 V$		0.8		nC
Q <sub>gd</sub>	Gate–Drain Charge			0.9		nC
Drain-So	ource Diode Characteristics	and Maximum Batings				
ls	Maximum Continuous Drain–Source				-1.2	Α
V <sub>SD</sub>	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$ , $I_S = -1.3 A$ (Note 2)		-0.8	1.3	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, l⊧ = −1.25A, dl⊧/dt = 100A/µs		17	100	nS

# **Typical Characteristics**

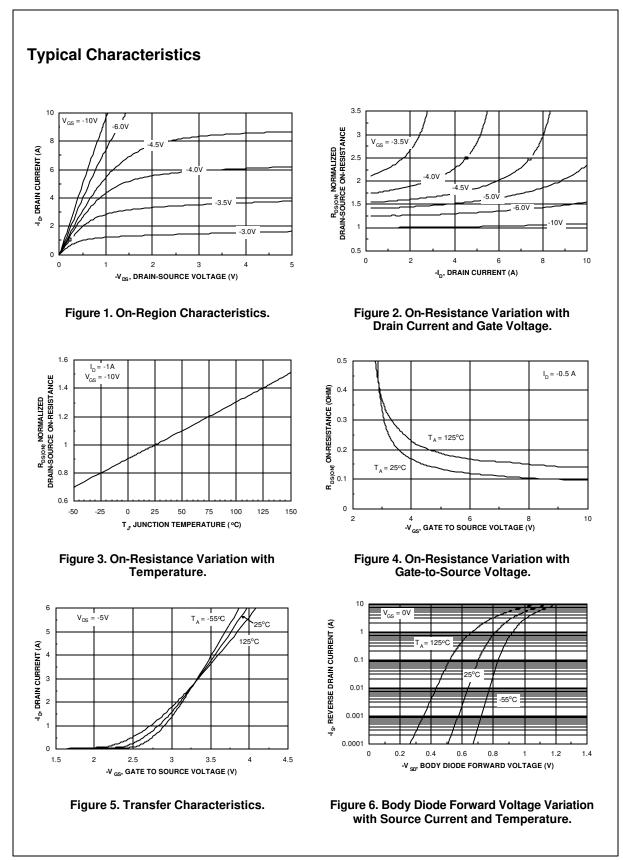
Notes:

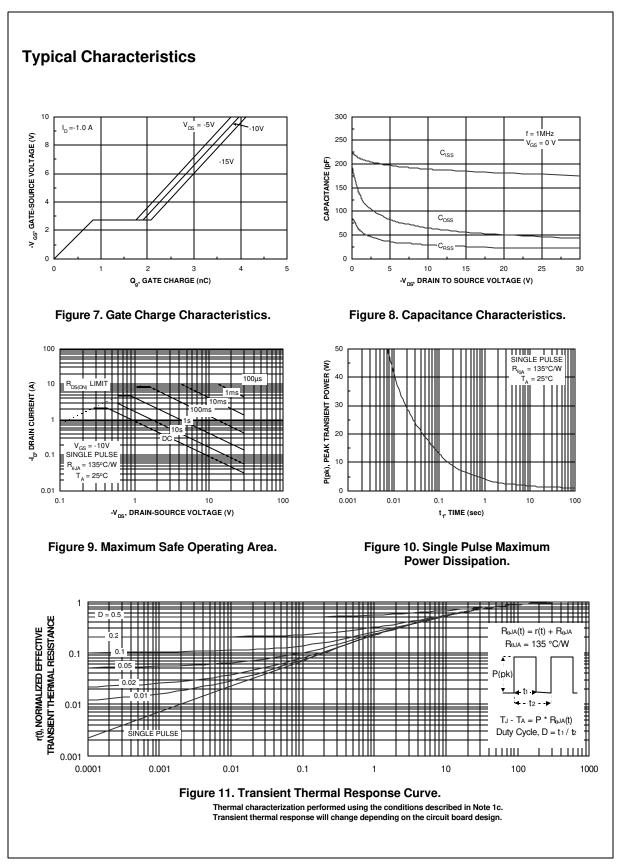
 R<sub>6UA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>6UC</sub> is guaranteed by design while R<sub>6CA</sub> is determined by the user's board design.



Scale 1 : 1 on letter size paper

2. Pulse Test: Pulse Width < 300 µs, Duty Cycle < 2.0%





FDS9953A Rev B(W)

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